

Spezifikationen	
Artikelnummer	FDMS9411L_F085
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET NCH 40V 30A POWER56
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2645 pcs Stock
VGS (th) (Max) @ Id	3V @ 250μA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	Power56
Serie	Automotive, AEC-Q101, PowerTrench®
Rds On (Max) @ Id, Vgs	7 mOhm @ 30A, 10V
Verlustleistung (max)	50W (Tj)
Verpackung	Original-Reel®
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1210pF @ 20V
Gate Charge (Qg) (Max) @ Vgs	28nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Tc)

sein:

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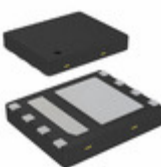
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 POWER56

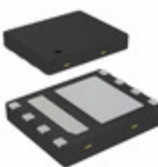
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FDMS9411_F085

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MOSFET N-CH 40V 8PQFN



Mehr

Contact us: **Info@YIC-Electronics.com**

HINZUFÜGEN: Einheit A5-B5 Nr. 509, 5 / F Sing Win-Fabrikgebäude, 15-17 Shing Yip Street, Kwun Tong, Kowloon, Hongkong.

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